

Developing a Server OS Drive for Big Data and Cloud Storage

C.C. Wu
EVP of Innodisk USA Corporation



- Boot up storage background
- Various mechanical designs
- Reliability
- Product Lifespan
- Performance



Background

- VMware ESXi, Microsoft Hyper-V, CentOS popular Server Operating Systems
- ESXi and Hyper-V require a minimum of 64GB for boot up storage
- CentOS requires 8GB for boot up storage
- Available form factors:
 - 2.5"
 - USB Drive
 - SD/microSD
 - SATADOM™
- mSATA/Slim
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- Small footprint form factor
- PLP design
- Lifespan issues
- 24/7 server uptime
- Kernel panics with bit errors
- Continuous log files
- Reliable Performance



Boot Up Storage Considerations

- 2.5" SSD occupy precious drive bay slots
- USB drives are consumer focused and lower quality
- SD Cards are similar to USB drives
- SATADOM™ combines all these benefits together



Form factor comparison















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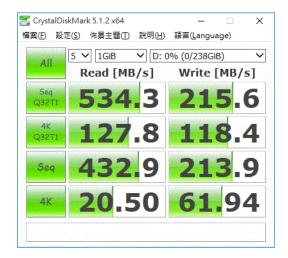
Flash Memory Interface / Performance

	SD UHS-II	USB3.1	SATA III	PCIe Gen3(NVMe)
Bus Speed	312MB/s	1.21GB/s	750MB/s	1GB/s Gen3 x1 2GB/s Gen3 x2 4GB/s Gen3 x4 M.2
Number of Queues			1	65536
Commands per Queue			32	65536
Application Flash Memory Summ Santa Clara, CA	Camera Storage	Portable Drive	Operation System Drive	Operation System Drive



Memory SATA Flash Storage - Mainstream

- Slim/mSATA/SATADOM™
- Internal Server boot up storage
- Advantages
 - Performance
 - Stable protocol
 - Design for OS
 - No External DRAM buffer



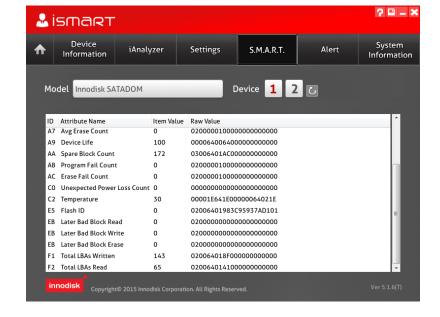


- Operation System cannot accept any single bit corruption... Cause kernel panic
- PLP design and external DRAM issue
- PE Cycle for MLC, iSLC, and TLC?
- Nonstop server



Flash Memory Product Lifespan

- iSMART tool
- LBA Write: TBW
- Flash Erase Count
 - MLC: 3,000.
 - iSLC:20,000
 - SLC:100,000



iAnalyzer: Analyses OS's loading

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Flash PE Cycle

Item	SLC Single Level Cell	i <mark>SLC</mark> SLC mode	MLC Multi Level Cell
	SLC Flash has only two states: erased (empty) or programmed (full).	Enhance iSLC, algorithm & Enhance ECC	MLC Flash has four states: erased (empty), 1/3, 2/3, and programmed (full).
Architecture	V _{Total} 1 0 SLC One bit per cell	MLC 00 01 10 10	V _{rost} 11 10 01 00 MLC Two bits per cell
Performance	Best	Faster	Slower
Power Consumption	Lowest	Lower	Higher
Endurance (P/E Cycles)	100K/60K	20К	зк
Initial Data Retention	10 Years	10 Years	10 Years
Density		MLC> iSLC>SLC	
Cost	***	***	**
Application	1.IPC, embedded, automation 2.Mission-critical applications	IPC/Kiosk/POS system Embedded System Server MB Write intended application.	POS, Kiosk system Commercial application



- Virtual Operation System has more loading with 4K random write.
- How to implement a FTL with low WA of 4K random write Without DRAM buffer
- Increase SRAM buffer
- 4K Mapping Algorithm
- Small Management Unit to reduce WAI

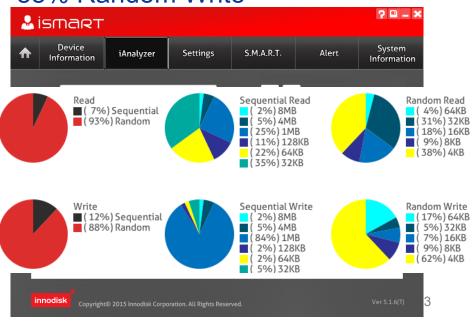


Install Microsoft Hyper-V Server 2012 R2

88% Random Write



	• 4.5 GB Wr	ite (14	13*32MB)
			? 🗆 🗆 🗙
ID	Attribute Name	Item Value	Raw Value
Α7	Avg Erase Count	0	0200000100000000000000
Α9	Device Life	100	00006400640000000000000
ΑА	Spare Block Count	172	03006401AC0000000000000
AB	Program Fail Count	0	0200000100000000000000
AC	Erase Fail Count	0	0200000100000000000000
C0	Unexpected Power Loss Count	0	000000000000000000000000000000000000000
C2	Temperature	30	00001E641E00000064021E
E5	Flash ID	0	02006401983C95937AD101
ЕВ	Later Bad Block Read	0	0200000000000000000000
ЕВ	Later Bad Block Write	0	0200000000000000000000
EB	Later Bad Block Erase	0	0200000000000000000000
F1	Total LBAs Written	143	020064018F000000000000
F2	Total LBAs Read	65	0200640141000000000000
	ID A7 A9 AA AB AC C0 C2 E5 EB EB F1	Attribute Name A7 Avg Erase Count A9 Device Life AA Spare Block Count AB Program Fail Count AC Erase Fail Count CO Unexpected Power Loss Count C2 Temperature E5 Flash ID EB Later Bad Block Read EB Later Bad Block Write EB Later Bad Block Erase F1 Total LBAs Written	ID Attribute Name Item Value A7 Avg Erase Count 0 A9 Device Life 100 AA Spare Block Count 172 AB Program Fail Count 0 AC Erase Fail Count 0 CO Unexpected Power Loss Count 0 C2 Temperature 30 E5 Flash ID 0 EB Later Bad Block Read 0 EB Later Bad Block Write 0 EB Later Bad Block Erase 0 F1 Total LBAs Written 143



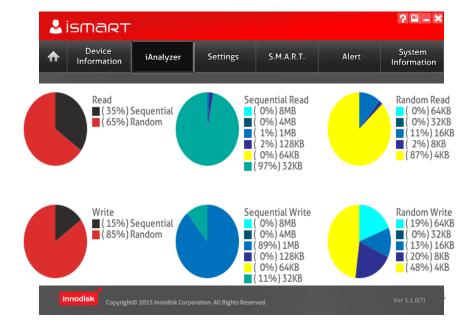


Flash Memory SMART Tool

- Install VM ESXi 6.0.0.0
- 512MB Write

? 😐 🗕 🗙 🚣 ismart Attribute Name Item Value Raw Value 0 Avg Erase Count 0200000100000000000000 A9 Device Life 100 00006400640000000000000 AA Spare Block Count 207 03006401CF000000000000 Program Fail Count 0 0200000100000000000000 AC Erase Fail Count 0 0200000100000000000000 Unexpected Power Loss Count 0 C2 Temperature 30 00001E641E00000064021E E5 Flash ID 0 02006401983C95937AD101 Later Bad Block Read 0 0200000000000000000000 Later Bad Block Write 0 0200000000000000000000 EB Later Bad Block Erase 0 0200000000000000000000 F1 Total LBAs Written 16 0200640110000000000000 F2 Total LBAs Read 2 0200640102000000000000

85% Random Write

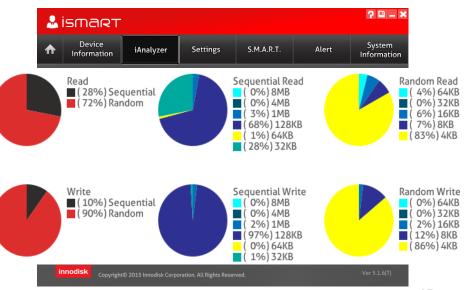




- Running over 12 Hours
- 544MB Write

	ismart		? □ = ×
ID	Attribute Name	Item Value	Raw Value
Α7	Avg Erase Count	0	02000001000000000000000
А9	Device Life	100	00006400640000000000000
AA	Spare Block Count	207	03006401CF000000000000
AB	Program Fail Count	0	020000100000000000000
AC	Erase Fail Count	0	020000100000000000000
co	Unexpected Power Loss Count	0	000000000000000000000000000000000000000
C2	Temperature	30	00001E641E00000064021E
E5	Flash ID	0	02006401983C95937AD101
EB	Later Bad Block Read	0	0200000000000000000000
EB	Later Bad Block Write	0	0200000000000000000000
EB	Later Bad Block Erase	0	0200000000000000000000
F1	Total LBAs Written	17	0200640111000000000000
F2	Total LBAs Read	76	020064014C000000000000

90% Random Write



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Memory NVMe Driver

- Microsoft Hyper-V:
 2008 R2 /2012/2012 R2 (Driver support)
- CentOS 7.0/ Kernel 3.3 :
 Support NVMe
- VMware:

ESXi 5.5/6.0 (Driver support)



Memory M.2 NVMe solution

- M.2 2242, 2280 SSD
- NO External DRAM
- PCle Gen 3
- NVMe protocol
- 4K Mapping FTL
- Up to 1GB/s by Gen3 x1





All	5 ✓ IGiB ✓ D: 0% (0/119GiB)		
	Read [MB/s]	Write [MB/s]	
Seq Q32T1	667. 9	192.0	
4K Q32T1	133.7	114.2	
Seq	619.7	189.8	
4K	16.69	73.93	

- PCle Gen 3 x1
- NVMe interface



- PCIe (NVMe) becomes the next generation mainstream server boot up drive
- SATA III currently on the market
- Small form factor is very popular
- 4K Mapping FTL is a good solution



Thank You!

C. C. Wu, EVP Innodisk USA

cc wu@Innodisk.com www.Innodisk.com